



REF1004

www.burr-brown.com/databook/REF1004.html

1.2V and 2.5V Micropower VOLTAGE REFERENCE

FEATURES

- INITIAL ACCURACY: REF1004-1.2 ±4mV REF1004-2.5 ±20mV
- MINIMUM OPERATING CURRENT: REF1004-1.2 10μA REF1004-2.5 20μA
- EXCELLENT LONG TERM TEMPERATURE STABILITY
- VERY LOW DYNAMIC IMPEDANCE
- OPERATES UP TO 20mA
- PACKAGE: 8-Lead SOIC

APPLICATIONS

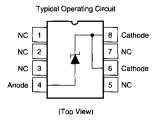
- BATTERY POWERED TEST EQUIPMENT
- PORTABLE MEDICAL INSTRUMENTATION
- PORTABLE COMMUNICATIONS DEVICES
- A/D AND D/A CONVERTERS
- NOTEBOOK AND PALMTOP COMPUTERS

DESCRIPTION

The REF1004-1.2 and REF1004-2.5 are two terminal bandgap reference diodes designed for high accuracy with outstanding temperature characteristics at low operating currents. Prior to the introduction of the REF1004 Micropower Voltage References, accuracy and stability specifications could only be attained by expensive screening of standard devices. The REF1004 is a cost effective solution when reference voltage accuracy, low power, and long term temperature stability are required.

REF1004 is a drop-in replacement for the LT1004 as well as an upgraded replacement of the LM185/385 series references. The REF1004C is characterized for operation from 0°C to 70°C and the REF1004I is characterized for operation from -40°C to +85°C.

The REF1004 is offered in an 8-lead Plastic SOIC package and shipped in anti-static rails or tape and reel.



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For Immediate Assistance, Contact Your Local Salesperson

SPECIFICATIONS

ELECTRICAL

At T₄ = +25°C, unless otherwise noted.

PARAMETER	CONDITIONS	REF1004-1.2		REF1004-2.5				
		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
REF1004C(1) REF1004I(2)	I _R = 100μA	1.231 1.229 1.225	1.235 1.235 1.235	1.239 1.239 1.239	2.490 2.487 2.480	2.500 2.500 2.500	2.511 2.511 2.511	٧
AVERAGE TEMPERATURE COEFFICIENT	I _{MIN} ≤ I _R ≤ 20mA		20			20		ppm/°C
MINIMUM OPERATION CURRENT ⁽³⁾			8	10		12	20	μА
REVERSE BREAKDOWN VOLTAGE CHANGE WITH CURRENT	$I_{MIN} \le I_R \le 1mA$ $1mA \le I_R \le 20mA$			1 1.5 ⁽³⁾ 10 20 ⁽³⁾			1 1.5 ⁽³⁾ 10 20 ⁽³⁾	mV
REVERSE DYNAMIC IMPEDANCE ⁽³⁾	I _R = 100μΑ		0.2	0.6		0.2	0.6	Ω
WIDE BAND NOISE (RMS) 10Hz ≤ I _R ≤ 10kHz	1 _R = 100µA		60			120		μ∨
LONG TERM STABILITY T _A = 25°C ± 0.1°C	I _R = 100μΑ		20	·		20		ppm/KH

NOTES: (1) This specification applies over the full operating temperature range of 0°C ≤ TA ≤ 70°C. (2) This specification applies over the full operating temperature range of 40°C ≤ T_A ≤ +85°C. (3) Denotes the specifications which apply over the full operating temperature range.

ORDERING INFORMATION

PRODUCT	T _A	v _z	PACKAGE
REF1004C-1.2	0°C to +70°C	1.2V	8-Lead SOIC
REF1004C-2.5	0°C to +70°C	2.5V	8-Lead SOIC
REF1004I-1.2	-40°C to +85°C	1.2V	8-Lead SOIC
REF1004I-2.5	-40°C to +85°C	2.5V	8-Lead SOIC

NOTE: Available in Tape and Reel, Add -TR to Model Number.

ABSOLUTE MAXIMUM RATINGS

Reverse Breakdown Current	
Forward Current	10mA
Operating Temperature Range	
REF1004C	0°C to +70°C
REF10041	-40°C to +85°C
Storage Temperature	
REF1004C	65°C to +150°C
REF1004I	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

PACKAGE INFORMATION

PRODUCT	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾
REF1004C-1.2	8-Pin SOIC	182
REF1004C-2.5	8-Pin SOIC	182
REF1004I-1.2	8-Pin SOIC	182
REF1004I-2.5	8-Pin SOIC	182

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

ORDERING INFORMATION

PRODUCT	PART MARKING
REF1004C-1.2	BBREF0412
REF1004C-2.5	BBREF0425
REF1004I-1.2	BBREF0412
REF1004I-2.5	BBREF0425



ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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